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## 08/223,739 | 160246: METHOD OF DEPOSITING A GALLIUM NITRIDE-BASED III-V GROUP COMPOUND SEMICONDUCTOR CRYSTAL LAYER

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Application Data

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Continuity

Patent Term Adjustment

Foreign Priority

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Address & Attorney/Agent Information

Supplemental Content

Assignments

Display References

Application #	Attorney Docket #	Patent #	Status	Filing or 371 (c) date
08/223,739	160246	5,433,169 Issued - 07/18/1995	Patent Expired Due to NonPayment of Maintenance Fees Under 37 CFR 1.362 - 08/13/2007	04/06/1994

Application type	Utility	Earliest publication #	-	Intl. registration # (Hague)	-
Examiner	ROBERT M KUNEMUND	Earliest publication date	-	Intl. registration publication date	-
Group art unit	1109	Assignee for publication	-		
Class/subclass	117/102.000	Confirmation #	7354		
AIA (first inventor to file)	No				
Entity status	Regular Undiscounted				

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